



#### 30V P-Channel Enhancement Mode MOSFET - ESD Protected

-0.5A

Voltage -30 V Current

#### **Features**

- RDS(ON), VGS@-4.5V, ID@-0.5A<390mΩ
- RDS(ON), VGS@-2.5V, ID@-0.3A<560mΩ</li>
- RDS(ON), VGS@-1.8V, ID@-0.1A<990mΩ</li>
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

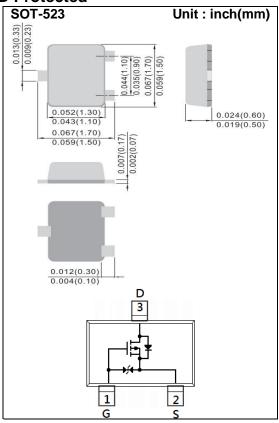
#### **Mechanical Data**

• Case: SOT-523 Package

• Terminals: Solderable per MIL-STD-750, Method 2026

Approx. Weight: 0.00007 ounces, 0.002 grams

Marking: E05



### **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	-30	V
Gate-Source Voltage		$V_{GS}$	<u>+</u> 8	V
Continuous Drain Current		I <sub>D</sub>	-0.5	А
Pulsed Drain Current		I <sub>DM</sub>	-2.0	Α
Power Dissipation	T <sub>a</sub> =25°C	$P_{D}$	300	mW
	Derate above 25°C		2.4	mW/°C
Operating Junction and Storage Tem	$T_J, T_{STG}$	-55~150	°C	
Typical Thermal resistance - Junction to Ambient (Note 3)		$R_{\theta JA}$	417	°C/W





# **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	$BV_{DSS}$	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-30	-	-	<b>V</b>	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=-250uA$	-0.5	-0.98	-1.3	<b>V</b>	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-0.5A	-	318	390	mΩ	
		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-0.3A	-	427	560		
		V <sub>GS</sub> =-1.8V, I <sub>D</sub> =-0.1A	-	853	990		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V	-	-0.01	-1	uA	
Gate-Source Leakage Current	$I_{GSS}$	V <sub>GS</sub> = <u>+</u> 8V, V <sub>DS</sub> =0V	-	<u>+</u> 3.2	<u>+</u> 10	uA	
Dynamic							
Total Gate Charge	$Q_g$	\/ 4E\/   0.EA	-	1.6	-	nC	
Gate-Source Charge	$Q_gs$	$V_{DS}$ =-15V, $I_{D}$ =-0.5A, $V_{GS}$ =-4.5V (Note 1,2)	-	0.5	-		
Gate-Drain Charge	$Q_gd$		-	0.3	-		
Input Capacitance	Ciss	V <sub>DS</sub> =-15V, V <sub>GS</sub> =0V, f=1.0MHZ	-	137	-	pF	
Output Capacitance	Coss		-	23	-		
Reverse Transfer Capacitance	Crss		-	10	-		
Switching							
Turn-On Delay Time	td <sub>(on)</sub>	$V_{DD}$ =-15V, $I_{D}$ =-0.5A, $V_{GS}$ =-4.5V, $R_{G}$ =6 $\Omega$ (Note 1,2)	-	11	-	ns	
Turn-On Rise Time	tr		-	52	-		
Turn-Off Delay Time	td <sub>(off)</sub>		-	65	-		
Turn-Off Fall Time	tf		-	46	-		
Drain-Source Diode							
Maximum Continuous Drain-Source	Is		-	-	-0.4	А	
Diode Forward Current							
Diode Forward Voltage	$V_{\text{SD}}$	I <sub>S</sub> =-1.0A, V <sub>GS</sub> =0V	-	-0.93	-1.2	V	

#### NOTES:

- 1. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited





#### TYPICAL CHARACTERISTIC CURVES

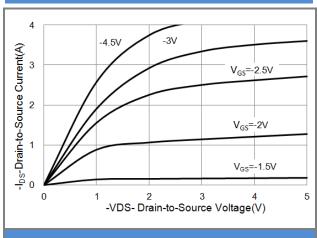
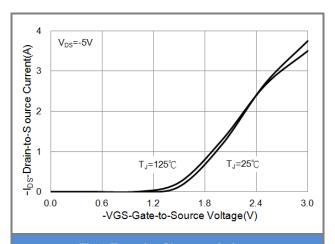


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

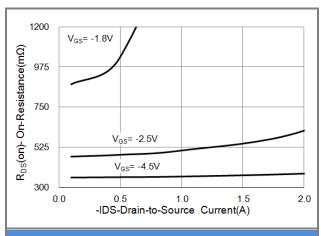


Fig.3 On-Resistance vs. Drain Current

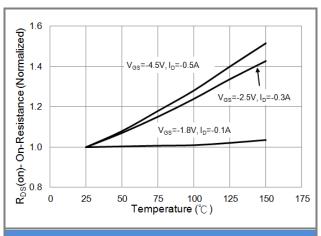


Fig.4 On-Resistance vs. Junction temperature

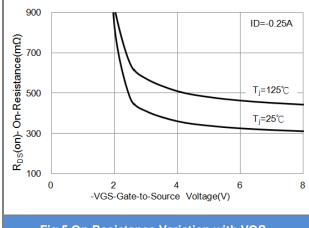


Fig.5 On-Resistance Variation with VGS.

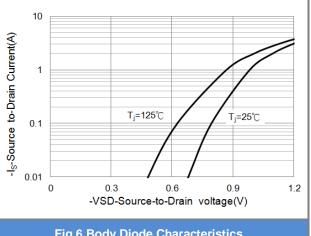


Fig.6 Body Diode Characteristics





#### **TYPICAL CHARACTERISTIC CURVES**

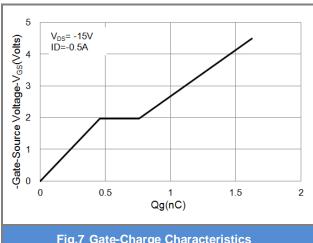


Fig.7 Gate-Charge Characteristics

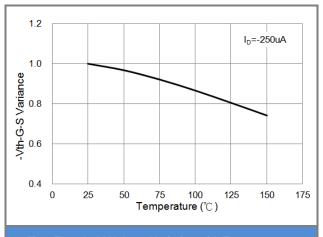


Fig.8 Threshold Voltage Variation with Temperature

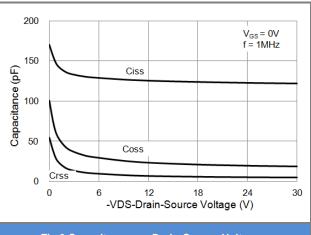


Fig.9 Capacitance vs. Drain-Source Voltage

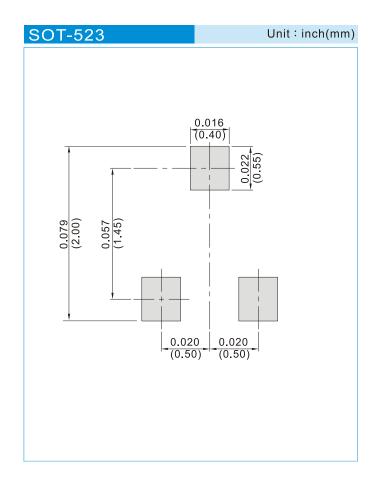




#### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJE8405_R1_00001	SOT-523	4K pcs / 7" reel	E05	Halogen free

### **MOUNTING PAD LAYOUT**







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DMN1006UCA6-7 DMN16M9UCA6-7 STF5N65M6 IRF40H233XTMA1 IPSA70R950CEAKMA1 IPSA70R2K0CEAKMA1 STU5N65M6
C3M0021120D DMN6022SSD-13